

# MURB1610CT / MURB1620CT

## **16A SURFACE MOUNT SUPER-FAST RECTIFIER**

#### **Features**

- Glass Passivated Die Construction
- Diffused Junction
- Super-Fast Recovery Times for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 100A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0

#### **Mechanical Data**

- Case: Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 1.7 grams (approx.)
- Mounting Position: Any



D <sup>2</sup> PAK					
Dim	Min	Max			
Α	9.65	10.69			
В	14.60	15.88			
С	0.51	1.14			
D	2.29	2.79			
Е	4.37	4.83			
G	1.14	1.40			
н	1.14	1.40			
J	8.25	9.25			
К	0.30	0.64			
L	2.03	2.92			
М	2.29	2.79			
All Dimensions in mm					

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	MURB1610CT	MURB1620CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	200	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	70	140	V
Average Rectified Output Current	@ $T_{C} = 125^{\circ}C$	lo	16		А
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		I <sub>FSM</sub>	100		А
Forward Voltage @ I <sub>F</sub> = 8.0A		V <sub>FM</sub>	0.975		V
Peak Reverse Current at Rated DC Blocking Voltage	$@T_A = 25^{\circ}C$ $@T_A = 150^{\circ}C$	I <sub>RM</sub>	5.0 250		μA
Maximum Recovery Time (Note 2)		t <sub>rr</sub>	25		ns
Typical Junction Capacitance (Note 3)		Cj	85		pF
Typical Thermal Resistance Junction to Case		Rejc	1.5		°C/W
Operating and Storage Temperature Range		Tj, TSTG	-65 to +150		°C

Notes: 1. Unit mounted on PC board with 5.0 mm<sup>2</sup> (0.013 mm thick) copper pad as heat sink.

- 2. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{rr} = 0.25A$ .
- 3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V DC.



